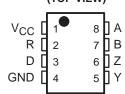
- High-Speed Low-Power LinBiCMOS™ Circuitry Designed for Signaling Rates<sup>†</sup> of up to 30 Mbps
- Bus-Pin ESD Protection Exceeds 12 kV HBM
- Very Low Disabled Supply-Current Requirements ... 700 μA Max
- Common-Mode Voltage Range of –7 V to 12 V
- Low Supply Current . . . 15 mA Max
- Compatible With ANSI Standard TIA/EAI-485-A and ISO8482: 1987(E)
- Positive and Negative Output Current Limiting
- Driver Thermal Shutdown Protection

#### description

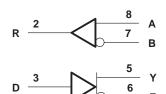
The SN65LBC179A and SN75LBC179A differential driver and receiver pairs are monolithic integrated circuits designed for bidirectional data communication over long cables that take on the characteristics of transmission lines. They are balanced, or differential, voltage mode devices that are compatible with ANSI standard TIA/EIA-485-A and ISO 8482:1987(E). The A version offers improved switching performance over its predecessors without sacrificing significantly more power.

The SN65LBC179A and SN75LBC179A combine a differential line driver and differential input line receiver and operate from a single 5-V supply. The driver differential outputs and the receiver differential inputs are connected to separate terminals for full-duplex operation and are designed to present minimum loading to the bus SN65LBC179AD (Marked as BL179A) SN65LBC179AP (Marked as 65LBC179A) SN75LBC179AD (Marked as LB179A) SN75LBC179AP (Marked as 75LBC179A) (TOP VIEW)

SLLS377C - MAY 2000 - REVISED JUNE 2001



logic diagram (positive logic)



**Function Tables** 

DRIVER						
INPUT OUTPUTS						
D	ΥZ					
Н	ΗL					
L	LH					
Open	ΗL					

RECEIVER						
DIFFERENTIAL INPUTS	OUTPUT					
A-B	R					
V <sub>ID</sub> ≥ 0.2 V	Н					
$-0.2 \text{ V} < \text{V}_{\text{ID}} < 0.2 \text{ V}$	?					
$V_{ID} \leq -0.2 V$	L					
Open circuit	Н					

H = high level, L = low level, ? = indeterminate

when powered off ( $V_{CC} = 0$ ). These parts feature a wide positive and negative common-mode voltage range making them suitable for point-to-point or multipoint data bus applications. The devices also provide positive-and negative-current limiting and thermal shutdown for protection from line fault conditions.

The SN65LBC179A is characterized over the industrial temperature range of  $-40^{\circ}$ C to  $85^{\circ}$ C. The SN75LBC179A is characterized for operation over the commercial temperature range of  $0^{\circ}$ C to  $70^{\circ}$ C.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

<sup>†</sup> Signaling rate by TIA/EIA-485-A definition restrict transition times to 30% of the bit length, and much higher signaling rates may be achieved without this requirement as displayed in the *TYPICAL CHARACTERISTICS* of this device.

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PRODUCTION DATA information is current as of publication date. Products conform to specifications per the terms of Texas Instruments standard warranty. Production processing does not necessarily include testing of all parameters.

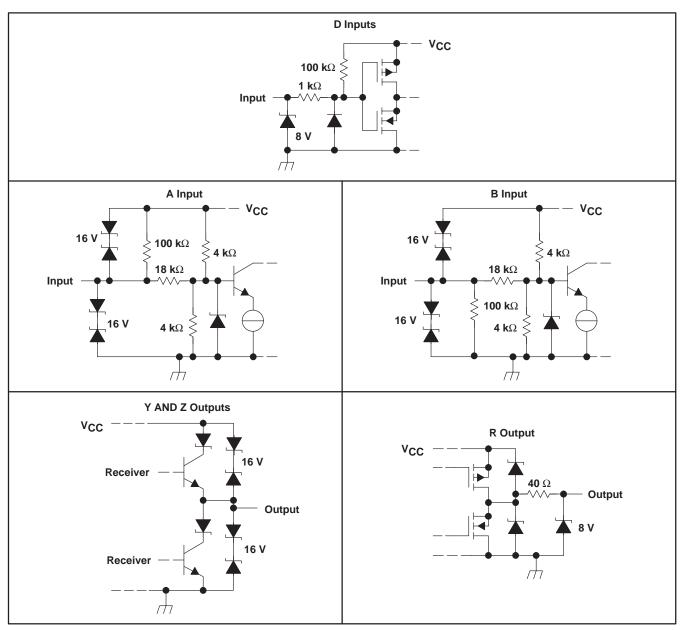


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SLLS377C - MAY 2000 - REVISED JUNE 2001

AVAILABLE OPTIONS						
	PACKAGE					
TA	SMALL OUTLINE (D)	PLASTIC DUAL-IN-LINE				
0°C to 70°C	SN75LBC179AD	SN75LBC179AP				
-40°C to 85°C	SN65LBC179AD	SN65LBC179AP				

### schematics of inputs and outputs





SLLS377C - MAY 2000 - REVISED JUNE 2001

#### absolute maximum ratings<sup>†</sup>

Supply voltage range, V <sub>CC</sub> (see Note 1)	–0.3 V to 6 V
Voltage range at A, B, Y, or Z (see Note 1)	–10 V to 15 V
Voltage range at D or R (see Note 1)	$\dots \dots -0.3$ V to V <sub>CC</sub> + 0.5 V
Electrostatic discharge: Bus terminals and GND, Class 3, A: (see Note 2)	12 kV
Bus terminals and GND, Class 3, B: (see Note 2)	400 V
All terminals, Class 3, A:	3 kV
All terminals, Class 3, B:	400 V
Continuous total power dissipation (see Note 3)	Internally limited
Total power dissipation	See Dissipation Rating Table
Storage temperature range, T <sub>stg</sub>	–65°C to 150°C
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds	260°C

<sup>†</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. All voltage values, except differential I/O bus voltages, are with respect to GND.

- 2. Tested in accordance with MIL-STD-883C, Method 3015.7
- 3. The maximum operating junction temperature is internally limited. Uses the dissipation rating table to operate below this temperature.

#### **DISSIPATION RATING TABLE**

PACKAGE	T <sub>A</sub> ≤ 25°C POWER RATING	DERATING FACTOR <sup>‡</sup> ABOVE T <sub>A</sub> = 25°C	T <sub>A</sub> = 70°C POWER RATING	T <sub>A</sub> = 85°C POWER RATING
D	725 mW	5.8 mW/°C	464 mW	377 mW
Р	1100 mW	8.08 mW/°C	640 mW	520 mW

<sup>‡</sup> This is the inverse of the junction-to-ambient thermal resistance when board-mounted and with no air flow.

#### recommended operating conditions

		MIN	NOM	MAX	UNIT
Supply voltage, V <sub>CC</sub>		4.75	5	5.25	V
High-level input voltage, VIH	D	2		VCC	V
Low-level input voltage, VIL	D	0		0.8	V
Differential input voltage, VID (see Note 4)		-12§		12	V
Voltage at any bus terminal (separately or common-mode), $V_{\mbox{O}},V_{\mbox{I}},orV_{\mbox{IC}}$	A, B, Y, or Z	-7		12	V
1 Park Loved a strend assessed 1	Y or Z	-60			
High-level output current, I <sub>OH</sub>	R	-8			mA
Level and and an average 1	Y or Z			60	
Low-level output current, IOL	R			8	mA
Operating free oir temperature Te	SN65LBC179A	-40		85	°C
Operating free-air temperature, T <sub>A</sub>	SN75LBC179A	0		70	C

§ The algebraic convention, in which the least positive (most negative) limit is designated as minimum, is used in this data sheet. NOTE 4: Differential input/output bus voltage is measured at the noninverting terminal with respect to the inverting terminal.



SLLS377C - MAY 2000 - REVISED JUNE 2001

### driver electrical characteristics over recommended operating conditions (unless otherwise noted)

PARAMETER		TEST CO	ONDITIONS	MIN	TYP†	MAX	UNIT
VIK	Input clamp voltage	l <sub>l</sub> = – 18 mA	I <sub>I</sub> = – 18 mA		-0.8		V
		R <sub>L</sub> = 54 Ω,	SN65LBC179A	1	1.5	3	
		See Figure 1	SN75LBC179A	1.1	1.5	3	
VOD	Differential output voltage	$R_L = 60 \Omega$ ,	SN65LBC179A	1	1.5	3	V
		−7 <v<sub>(tot) &lt; 12, See Figure 2</v<sub>	SN75LBC179A	1.1	1.5	3	
$\Delta  V_{OD} $	Change in magnitude of differential output voltage (see Note 5)	See Figures 1 and	-0.2		0.2	V	
V <sub>OC(SS)</sub>	Steady-state common-mode output voltage			1.8	2.4	2.8	V
$\Delta VOC(SS)$	Change in steady-state common-mode output voltage (see Note 5)	See Figure 1		-0.1		0.1	V
IO	Output current with power off	V <sub>CC</sub> = 0,	$V_{O} = -7 V$ to 12 V	-10	±1	10	μΑ
Iн	High-level input current	V <sub>I</sub> = 2.V		-100			μA
۱ <sub>IL</sub>	Low-level input current	VI = 0.8 V		-100			μA
IOS	Short-circuit output current	$-7 \text{ V} \le \text{V}_0 \le 12 \text{ V}$		-250	±70	250	mA
ICC	Supply current	No load,	$A^{I} = 0 \text{ or } A^{CC}$		8.5	15	mA

<sup>†</sup> All typical values are at V<sub>CC</sub> = 5 V, T<sub>A</sub> = 25°C. NOTE 5:  $\Delta$ |V<sub>OD</sub>| and  $\Delta$ |V<sub>OC</sub>| are the changes in the steady-state magnitude of V<sub>OD</sub> and V<sub>OC</sub>, respectively, that occur when the input is changed from a high level to a low level.

#### driver switching characteristics over recommended operating conditions (unless otherwise noted)

	PARAMETER		TEST CONDITIONS			MAX	UNIT
<sup>t</sup> PLH	Propagation delay time, low-to-high-level output			2	6	12	ns
<sup>t</sup> PHL	Propagation delay time, high-to-low-level output			2	6	12	ns
t <sub>sk(p)</sub>	Pulse skew (  tpHL - tpLH )	$R_L = 54 \Omega$ , See Figure 3	C <sub>L</sub> = 50 pF,		0.3	1	ns
t <sub>r</sub>	Differential output signal rise time	occ rigare o		4	7.5	11	ns
tf	Differential output signal fall time	1		4	7.5	11	ns



SLLS377C - MAY 2000 - REVISED JUNE 2001

### **RECEIVER SECTION**

# receiver electrical characteristics over recommended operating conditions (unless otherwise noted)

	PARAMETER	TEST CONDITIONS		MIN	TYP	MAX	UNIT
$V_{IT+}$	Positive-going input threshold voltage	$I_{O} = -8 \text{ mA}$				0.2	
VIT-	Negative-going input threshold voltage						V
V <sub>hys</sub>	Hysteresis voltage (V <sub>IT +</sub> – V <sub>IT –</sub> )	1 <sub>O</sub> = 8 mA			50		mV
VOH	High-level output voltage	$V_{ID}$ = 200 mV, $I_{OH}$ = -8 mA, See Figure 1		4	4.9		V
VOL	Low-level output voltage	$V_{ID} = -200 \text{ mV}, I_{OL} = 8 \text{ mA}, \text{ See Figure 1}$			0.1	0.8	V
		V <sub>IH</sub> = 12 V, V <sub>CC</sub> = 5 V			0.4	1	
II	Bus based arms of	$V_{IH} = 12 V$ , $V_{CC} = 0$			0.5	1	
	Bus input current	$V_{IH} = -7 V$ , $V_{CC} = 5 V$	Other input at 0 V	-0.8	-0.4		mA
		$V_{IH} = -7 V$ , $V_{CC} = 0$		-0.8	-0.3		

# receiver switching characteristics over recommended operating conditions (unless otherwise noted)

	PARAMETER	TEST CONDITIONS		TYP	MAX	UNIT
<sup>t</sup> PLH	Propagation delay time, low-to-high-level output		7	13	20	ns
<sup>t</sup> PHL	Propagation delay time, high-to-low-level output	$V_{ID} = -1.5 V$ to 1.5 V, See Figure	4 7	13	20	ns
tsk(p)	Pulse skew (  t <sub>PLH</sub> – t <sub>PHL</sub>  )			0.5	1.5	ns
tr	Rise time, output			2.1	3.3	ns
tf	Fall time, output	See Figure 4		2.1	3.3	ns

### PARAMETER MEASUREMENT INFORMATION

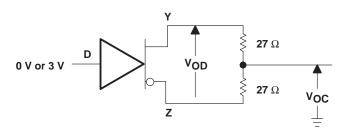
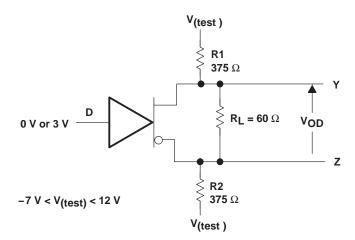


Figure 1. Driver  $V_{\mbox{\scriptsize OD}}$  and  $V_{\mbox{\scriptsize OC}}$ 

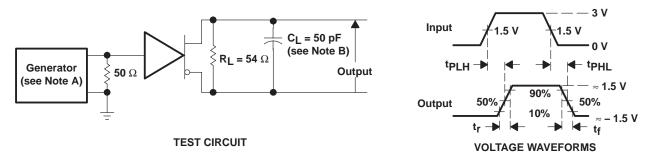


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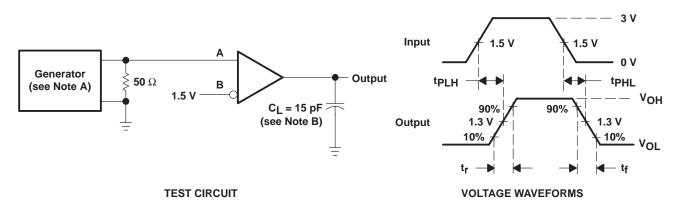
#### PARAMETER MEASUREMENT INFORMATION





- NOTES: A. The input pulse is supplied by a generator having the following characteristics: PRR  $\leq$  1 MHz, 50% duty cycle, t<sub>f</sub>  $\leq$  6 ns, t<sub>f</sub>  $\leq$  6 ns, Z<sub>O</sub> = 50  $\Omega$ .
  - B. CL includes probe and jig capacitance.

Figure 3. Driver Test Circuits and Voltage Waveforms

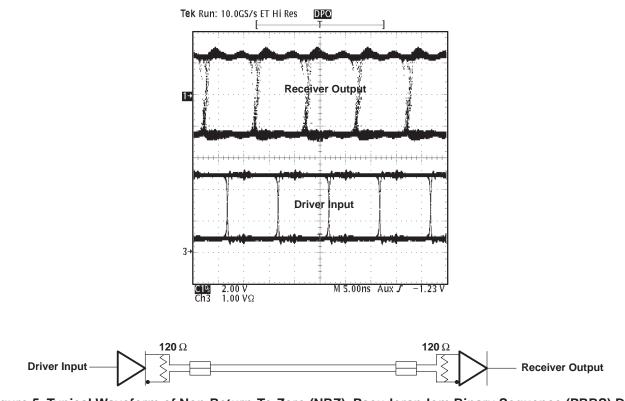


- NOTES: A. The input pulse is supplied by a generator having the following characteristics: PRR  $\leq$  1 MHz, 50% duty cycle, t<sub>f</sub>  $\leq$  6 ns, t<sub>f</sub>  $\leq$  6 ns, Z<sub>O</sub> = 50  $\Omega$ .
  - B. CL includes probe and jig capacitance.

#### Figure 4. Receiver Test Circuit and Voltage Waveforms



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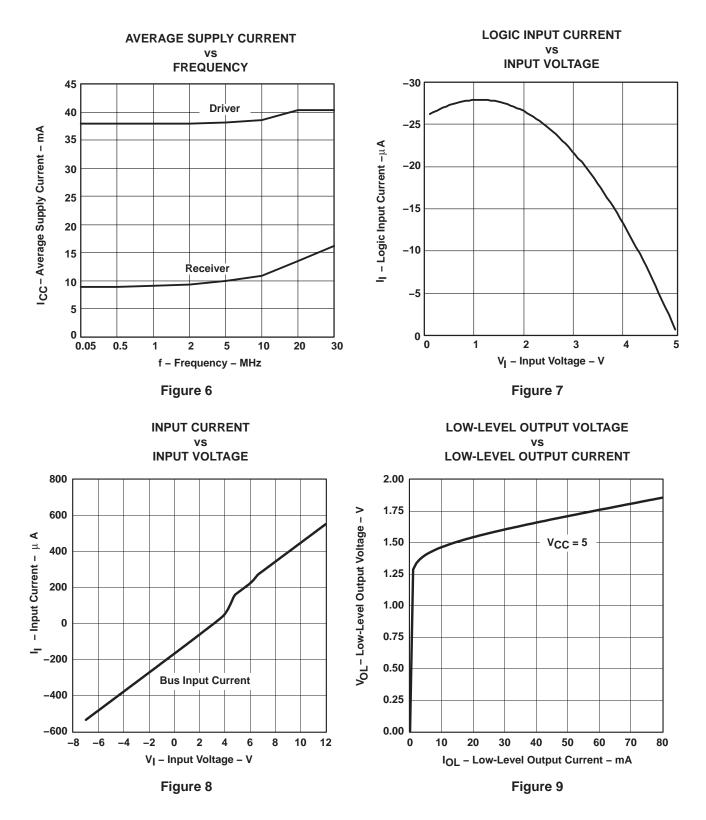
### **TYPICAL CHARACTERISTICS**

# Figure 5. Typical Waveform of Non-Return-To-Zero (NRZ), Pseudorandom Binary Sequence (PRBS) Data at 100 Mbps Through 15m, of CAT 5 Unshielded Twisted Pair (UTP) Cable

TIA/EIA-485-A defines a maximum signaling rate as that in which the transition time of the voltage transition of a logic-state change remains less than or equal to 30% of the bit length. Transition times of greater length perform quite well even though they do not meet the standard by definition.



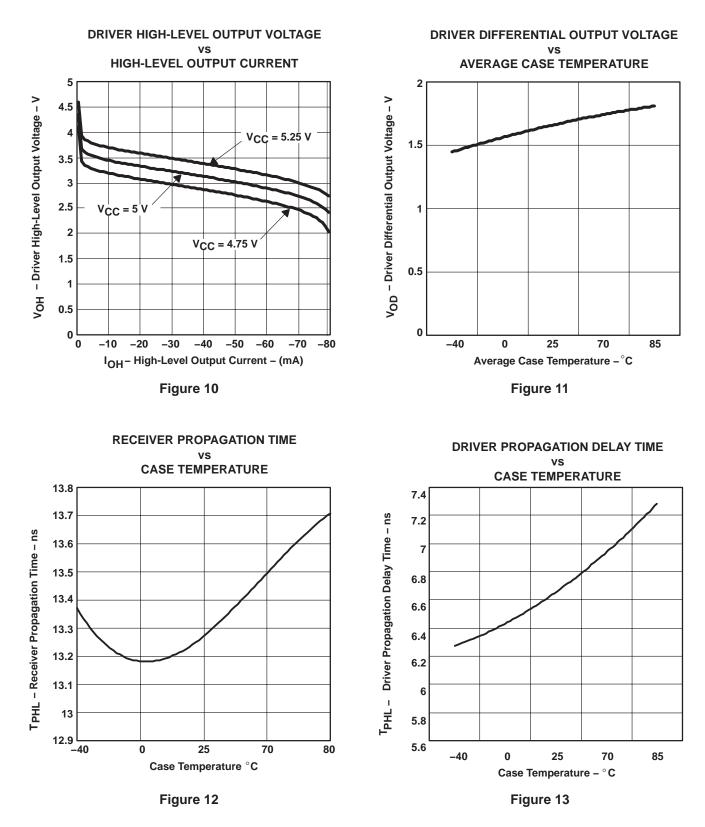
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### **TYPICAL CHARACTERISTICS**



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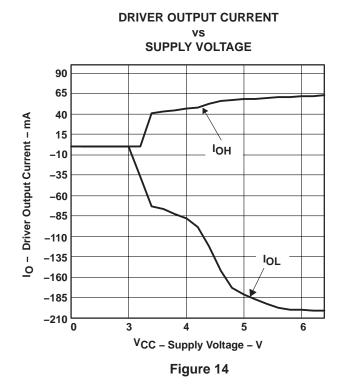


### TYPICAL CHARACTERISTICS



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### **TYPICAL CHARACTERISTICS**





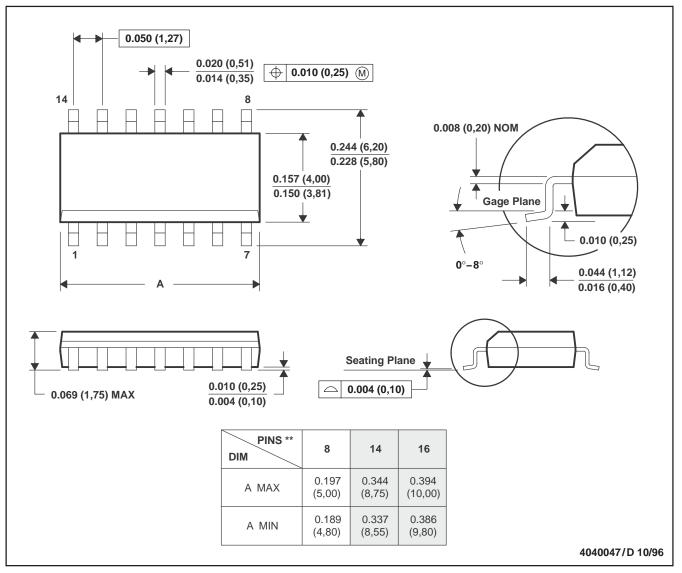
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#### **MECHANICAL INFORMATION**

#### D (R-PDSO-G\*\*)

#### PLASTIC SMALL-OUTLINE PACKAGE





NOTES: A. All linear dimensions are in inches (millimeters).

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion, not to exceed 0.006 (0,15).

D. Falls within JEDEC MS-012



SLLS377C - MAY 2000 - REVISED JUNE 2001

P (R-PDIP-T8)

**MECHANICAL INFORMATION** 

PLASTIC DUAL-IN-LINE

0.400 (10,60) 0.355 (9,02) 8 5 0.260 (6,60) 0.240 (6,10) 0 ¥. 1 4 0.070 (1,78) MAX 0.325 (8,26) 0.020 (0,51) MIN 0.300 (7,62) 0.015 (0,38) ¥ **Gage Plane** 0.200 (5,08) MAX 4 Seating Plane 0.010 (0,25) NOM 0.125 (3,18) MIN 0.430 (10,92) -0.100 (2,54) MAX 0.021 (0,53) 🔶 0.010 (0,25) 🕅 0.015 (0,38) 4040082/D 05/98

- NOTES: A. All linear dimensions are in inches (millimeters).
  - B. This drawing is subject to change without notice.
  - C. Falls within JEDEC MS-001

For the latest package information, go to http://www.ti.com/sc/docs/package/pkg\_info.htm



#### **PACKAGING INFORMATION**

Orderable Device	Status <sup>(1)</sup>	Package Type	Package Drawing	Pins	Package Qty	Eco Plan <sup>(2)</sup>	Lead/Ball Finish	MSL Peak Temp <sup>(3)</sup>
SN65LBC179AD	ACTIVE	SOIC	D	8	75	Pb-Free (RoHS)	CU NIPDAU	Level-2-260C-1YEAR/ Level-1-220C-UNLIM
SN65LBC179ADR	ACTIVE	SOIC	D	8	2500	Pb-Free (RoHS)	CU NIPDAU	Level-2-260C-1YEAR/ Level-1-220C-UNLIM
SN65LBC179AP	ACTIVE	PDIP	Р	8	50	Pb-Free (RoHS)	CU NIPDAU	Level-NC-NC-NC
SN65LBC179APE4	ACTIVE	PDIP	Р	8	50	None	Call TI	Call TI
SN75LBC179AD	ACTIVE	SOIC	D	8	75	Pb-Free (RoHS)	CU NIPDAU	Level-2-260C-1YEAR/ Level-1-220C-UNLIM
SN75LBC179ADR	ACTIVE	SOIC	D	8	2500	Pb-Free (RoHS)	CU NIPDAU	Level-2-260C-1YEAR/ Level-1-220C-UNLIM
SN75LBC179AP	ACTIVE	PDIP	Р	8	50	Pb-Free (RoHS)	CU NIPDAU	Level-NC-NC-NC
SN75LBC179APE4	ACTIVE	PDIP	Р	8	50	None	Call TI	Call TI

<sup>(1)</sup> The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) Eco Plan - May not be currently available - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

None: Not yet available Lead (Pb-Free).

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<sup>(3)</sup> MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDECindustry standard classifications, and peak solder temperature.

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